TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington Power Transistor)

# 2SD1525

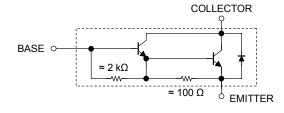
### **High Current Switching Applications**

- High collector current: IC = 30 A
- High DC current gain:  $h_{FE} = 1000$  (min) ( $V_{CE} = 5$  V,  $I_{C} = 20$  A)
- Monolithic construction with built-in base-emitter shunt resistor.

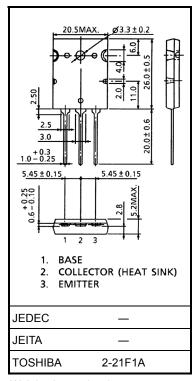
## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	100	V
Collector-emitter voltage	V <sub>CEO</sub>	100	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	30	Α
Base current	lΒ	5	Α
Collector power dissipation (Tc = 25°C)	P <sub>C</sub>	150	W
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

## **Equivalent Circuit**



Unit: mm

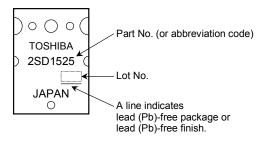


Weight: 9.75 g (typ.)

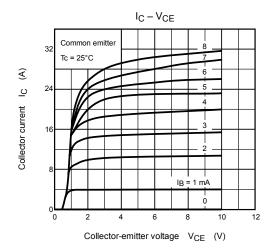
# Electrical Characteristics (Ta = 25°C)

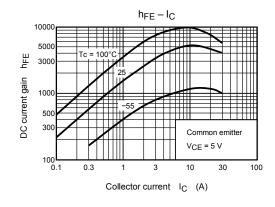
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	_	_	100	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	10	mA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	100	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 20 A	1000	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 30 A	200	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>		_	_	1.5	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 20 A, I <sub>B</sub> = 0.2 A	_	_	2.5	V
Emitter-collector forward voltage		V <sub>ECF</sub>	I <sub>E</sub> = 10 A, I <sub>B</sub> = 0	-	_	3	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	_	10	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	500	_	pF
Switching time S	Turn-on time	t <sub>on</sub>	$V_{CC} = 50 \text{ V}$ $CC$ $OC$ $OC$ $OC$ $OC$ $OC$ $OC$ $OC$	_	1.5	_	
	Storage time	t <sub>stg</sub>			10	_	μs
	Fall time	t <sub>f</sub>			1.5	_	

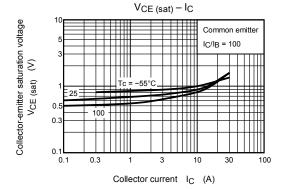
# Marking

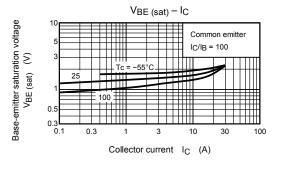


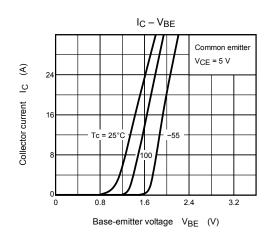
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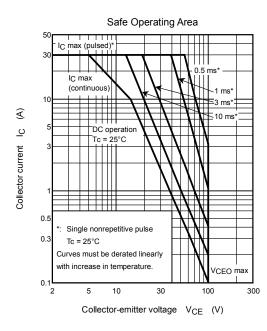












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